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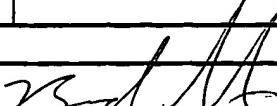
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Substitute for form 1449A/PTO				Complete if Known	
				Application Number	New Application
				Filing Date	August 27, 2003
				First Named Inventor	Ritsuko KAWASAKI et al.
				Group Art Unit	2818
				Examiner Name	Q. Hoang
Sheet	1	of	1	Attorney Docket Number	740756-2645

U.S. PATENT DOCUMENTS					
Examiner Initials ¹	Cited No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
		Number	Kind Code ² (if known)		
ZKS		US-5,612,251		Lee	03/18/1997
		US-5,767,003		Noguchi	06/16/1998
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FOREIGN PATENT DOCUMENTS						
Examiner Initials ¹	Cited No.	Foreign Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Office ³	Number ⁴			
ZKS	JP	08-228006 A			09/03/1996	
ZKS	JP	07-130652 A			05/19/1995	Abstract

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS					
Examiner Initials ¹	Cited No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
ZKS		K. Shimizu, O. Sugiura, M. Matsumura, "High Mobility Poly-Si Thin Film Transistors Fabricated by a Novel Excimer Laser Crystallization Method", IEEE Transactions on Electron Devices, Vol., 40, No. 1, pp. 112-117, January, 1993.			

Examiner Signature		Date Considered	8/15/04
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¹Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁵ Applicant is to place a check mark here if English language Translation is attached.

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